10/593897

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: Hideomi KOINUMA et al.

Application Number: Not yet assigned

Filed: September 22, 2006

For: FLUX ASSISTED SOLID PHASE EPITAXY

Attorney Docket Number:

063060

Customer Number:

38834

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450 September 22, 2006

Sir:

In compliance with 37 C.F.R. §1.56, Applicants direct the attention of the Patent and Trademark Office to the documents listed on the attached PTO/SB/08. A copy of each non- U.S. document is enclosed herewith.

If there are any fees due in connection with the filing of this paper, please charge Deposit Account No. <u>50-2866</u>.

Respectfully submitted,

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Enclosure: PTO/SB/08, 9 documents and Int'l Search Report

1AP16 Rec'd PCT/PTO 22 SEP 2006 10/593897

Combined Form PTO/SB/08A&B				Complete if Known		
Combined Form F10/Sb/06/	ACD			Application Number	New Application	
INFORM	ATION DISC	CLOS	URE	Confirmation Number		
- STATEMENT BY APPLICANT			ANT	Filing Date	September 22, 2006	
				First Named Inventor	Hideomi KOINUMA et al.	
(use as many sheets as necessary)				Art Unit		
•				Examiner Name		
Sheet	1	of	1	Attorney Docket Number	063060	

U.S. PATENT DOCUMENTS						
Examiner Cite Initials* No.1	Document 1	Number	Publication Date			
		Number	Kind Code ² (if known)	MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	
		US				
		US				
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FOREIGN PATENT DOCUMENTS							
	Cite	Fo	oreign Patent Document		Publication Date	Name of Patentee or	
	No.1	Country Code ³	Number ⁴	Kind Code ⁵ (if known)	MM-DD-YYYY	Applicant of Cited Document	Translation ⁶
	1	JР	2-64098	A	03-05-1990	NEC CORP	Abstract, cited in ISR
	2	JР	2-289496	A	11-29-1990	TOSOH CORP	Abstract, cited in ISR
	3	JР	7-57535	A	03-03-1995	TDK CORP	Abstract, cited in ISR
	4	JР	7-126834	A	05-16-1995	JAPAN STEEL WORKS LTD: THE	Abstract, cited in ISR
	5	JР	2002-68893	A	03-08-2002	Japan Science & Technology Corp.	Abstract, cited in ISR
	6	Љ	2005-1987	A	01-06-2005	Japan Science & Technology Agency	Abstract, cited in ISR

Examiner Cite Initials* No.1		Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.				
	7	Takeshi KIJIMA et al., "New Low-Temperature Processing of Metalorganic Chemical Vapor Deposition-Bi ₄ Ti ₃ O ₁₂ Thin Films Using BiOx Buffer Layer", Jpn. J. Appl. Phys. Vol. 38 (1999) pp. 127-130.	Yes			
	8	X.Q. PAN et al., "Domain structure of epitaxial Bi ₄ Ti ₃ O ₁₂ thin films grown on (001) SrTiO ₃ substrates", APPLIED PHYSICS LETTERS Vol. 83, No. 12, 22 September 2003, pp. 2315-2317.	Yes			
	9	K.S.YUN, "Tri-Phase Epitaxy", Journal of the Metallurgical Society of Japan Vol. 66, No. 4, (2002), pp. 284-288.	Abstract			
	10	International Search Report of PCT/JP2005/005642 date of mailing June 7, 2005				

Examiner Signature	Date Considered	

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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